

Area Efficiency in Neuromorphics on Constrained Devices

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ABSTRACT

Resource-constrained devices form the foundation of the Internet of Things (IoT) era. Because IoT aims to create highly interconnected environments using small devices with limited computational, energy, and area resources, numerous control systems have been designed to operate efficiently as IoT edge devices while minimizing power and hardware overhead. Recently, researchers have explored integrating machine learning into control systems built on such constrained platforms. However, achieving low power consumption and minimal area utilization while maintaining high application performance remains a significant challenge. Spiking neuromorphic computing (SNC) is an emerging paradigm well suited to resource-constrained devices and a range of emerging applications. In addition to enabling machine-learning capabilities, SNC significantly reduces energy consumption. For instance, low-energy memory technologies such as memristors are commonly employed to support power-efficient operation while further reducing system area. Overall, SNC is expected to deliver computational efficiency comparable to deep learning, while operating within the strict power and resource limitations of constrained devices.

• **Computer systems organization** → **Neural networks; Embedded hardware;**

KEYWORDS

Neuromorphic; memristor; internet of things; machine learning

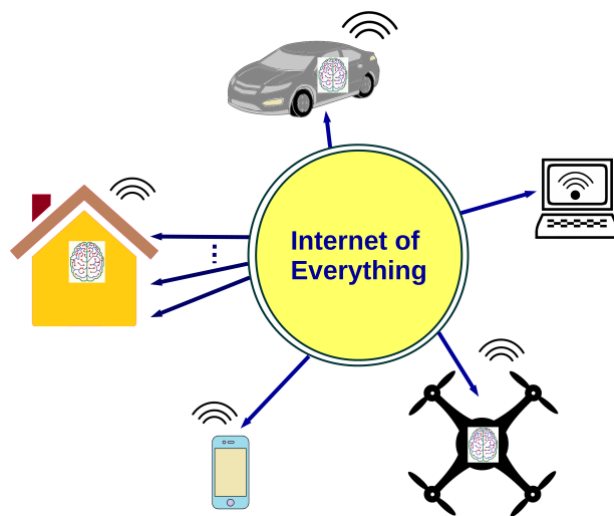


Figure 1: Neuromorphic computing in IoT edge devices.

1 INTRODUCTION

Internet of things applications (IoT) (Fig. 1) are emerging in which many resource constrained devices that compose such systems can benefit from machine learning capabilities. For example, autonomous drone applications can include simple neural networks which actively learn and adapt to subtle variations that will occur as they navigate their environment. Such capability can be particularly advantageous for applications where the drones are used to search for survivors in a disaster zone (e.g., a collapsed building), to provide one example. While such capability would certainly be advantageous, a real challenge exists in providing such on-the-fly learning in systems with limited area and power supply.

Several recent works have explored how deep learning neural networks can be leveraged for resource constrained systems [1] – [10]. For example, Leroux *et al.* specifically demonstrated how cascaded neural network layers can achieve small error rates when classifying MNIST characters using IoT devices [11]. Similarly, Motamedi *et al.* demonstrate a system-on-chip (SoC) implementation for convolutional neural networks (CNN) that is particularly useful at reducing the number of threads, and thus power, required for deep learning applications [15]. The prior work in this area has made

some important steps toward constructing more efficient deep learning systems for IoT. However, it is the premise of this work that the extreme resource constrained nature IoT demands a more careful study of neuromorphic approaches that are inherently more area and energy efficient than any deep learning approach. Thus, we focus our attention on sparse recurrent neural networks (RNN) that exhibit significant area and energy savings relative to their CNN counterparts.

In [18], Schuman and Birdwell present a genetic algorithm based technique, evolutionary optimization (EO), tailored for implementing area-efficient spiky neuromorphic networks. Typically, EO produces sparse RNN neural networks (small, energy-efficient) that run on the corresponding neuro-inspired dynamic architecture (NIDA) [17]. Further, simplicity in the number and type of parameters is a key feature of the NIDA architecture, making it particularly area and energy efficient relative to other neuromorphic approaches. Thus, NIDA-style systems are particularly well suited for resource constrained IoT systems. While NIDA is itself a high-level architecture (typically only simulated), our group has also begun development on a NIDA-based memristive dynamic adaptive neural network architecture (mrDANNA) [4] that can one day be leveraged in IoT hardware implementations.

Normally for analysis of large or streaming datasets like those from the sensors within IoT devices, data analysis is performed using deep neural networks (DNN's). Traditionally, to avoid needing massive compute power at edge devices, the data is compressed, encrypted, and then broadcast to a data center to handle the calculation, and the response is then sent back to the device. Performing the connection remotely uses much less power than doing the calculation at the endpoint, but this can be slow, insecure, and unreliable in areas without a strong network infrastructure [19]. To avoid these problems, some devices include more powerful processors and more efficient deep learning algorithms to either do all of the deep learning work on-device or process some layers of the DNN on device before sending a smaller message to the remote compute facility [12, 19]. Adding more traditional computing power to a given IoT device may not be desirable or even possible, so work on small, low-power devices is needed.

2 BACKGROUND

2.1 Nano-scale Memristors

Leon O. Chua first introduced the theory behind “memristors” (or “memory resistors”) [6] in 1971. A memristor in more recent terms typically refers to a two terminal nanoscale non-volatile device whose resistance can be modulated by the magnitude of voltage across the device and the time for which the voltage is applied. A memristor can attain multiple resistance levels between the two bounds known as the low resistance state (LRS) and the high resistance state (HRS). The LRS and HRS of any memristor is dependent on the switching material, process conditions, noise and environmental conditions. Since memristors are very small in size, they are particularly attractive for designing area efficient systems. Moreover, the energy consumption of a memristor tends to be very low as well, especially for devices whose LRS is relatively large. Hence, memristors have been attractive to the energy efficient neuromorphic chip designer. The used-based switching characteristics

of memristors also make them useful for implementing synaptic circuits. Several neuromorphic architectures have been proposed in recent years which leverage a variety of memristive switching materials [10, 13, 20].

The memristor model we have used in this paper is based on [1]. This model was developed from on experimental results for nanoscale hafnium-oxide (HfO_x) memristors fabricated within a 65 nm CMOS process [2, 3]. Fig. 2 shows the current-voltage relationship for an example HfO_x memristor, specifically illustrating the characteristics of the device when switching between the LRS and HRS resistance states. When a voltage greater than a threshold of 1V is applied across the memristor, the device will switch from HRS to LRS. Likewise, an applied voltage less than the negative threshold of about $-0.7V$ will cause the device to switch from LRS to HRS. In both cases, the voltage applied should also be held for at least a minimum “switching time” (typically 10 – 100ns) in order to switch fully between the two extreme resistance states, HRS and LRS. Resistance states between LRS and HRS are also achievable by applying short, nanosecond pulses that essentially “nudge” the resistance. This variety and range of resistance is particularly useful for representing synaptic weights in the spiky neuromorphic model considered. The ability to change these resistance values with controlled pulses is also leveraged to implement online learning mechanisms such as spike time-dependent plasticity (STDP) [4].

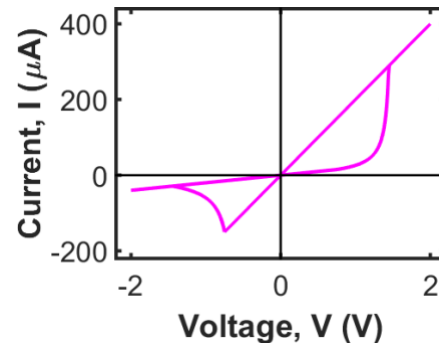


Figure 2: I-V characteristics of memristor model.

2.2 Neuromorphic ASIC Design

Resource constrained IoT devices are always in need of devices and techniques that consume less power and energy, as these are the major constraints for compact systems with limited battery supply. Hence, memristor-based spiky neuromorphic computing architectures are particularly attractive as viable solutions for IoT based machine learning. Moreover, several emergent nano-scale devices (memristors included) are being leveraged in such systems that promise lower area and power consumption [7, 8, 16]. For our part, non-volatile memristors have been used to design synapses that help to ensure low energy consumption while storing synaptic weights. Different materials and their corresponding devices will exhibit differences in energy consumption. For instance, if we consider HfO_x , the energy while the synapse is active, idle and

learning is detailed on Table 1. Here, the active phase of the synapse refers to the mode of operation; the idle phase defines the inactive condition and the learning phase includes both the potentiation and the depression of the synaptic weights based on the neuron fires. Each of these synapse states consumes energy depending on the type of memristive device used and the peripheral control circuitry.

Table 1: Energy values for HfO_x synapses [4]

Synapse state	Energy per spike (pJ)
<i>Active</i>	0.48
<i>Idle</i>	0.002
<i>Learninđ (IncreaseWeidht)</i>	0.26
<i>Learninđ (DecreaseWeidht)</i>	0.13

Mixed-signal CMOS neurons can also be designed for energy and area efficiency, specifically when using CMOS integrate-and-fire neurons consisting of very few transistors [5]. The primary concern in terms of area is the size of the capacitors. Capacitor area can also be mitigated via the use of different memristors that will in turn ensure proper incoming current flow into the neuron. The mixed-signal neuron operates in three different phases: *accumulation*, *idle* and the *firinđ* phases. Energy consumed by the neuron during these phases are listed on Table 2. Here the accumulation energy refers to the energy consumed while accumulating incoming charge/spikes from the synaptic weights. The idle energy is comparatively low since the neuron’s functionality is mostly inactive with the exception of peripheral circuitry. Unlike the synapse phases, the neuron does not consume energy specifically relating to the learning process. Instead, the neuron consumes energy while it produces firing spikes. This energy involves the generation of a post-neuron fire when the accumulated charge crosses over the threshold of that particular neuron. Moreover, the shaping of the firing spike is also an important factor for energy consumption since the generated firing pulses would be fed into the next stage of neuromorphic cores.

Table 2: Energy values for CMOS neurons [4]

Neuron phase	Energy per spike (pJ)
<i>Accumulation</i>	9.81
<i>Idle</i>	7.2
<i>Firinđ</i>	12.5

The neuromorphic architecture (mrDANNA) we consider is mixed-signal in nature. Hence the architecture is significant for low power and area efficiency and includes both the synapse and neuron model described. Several synapses and neurons are gathered to turn into some memristive neuromorphic core which we call mrDANNA cores. Each core contains energy efficient memristive synapses and an analog IAF neuron. The total layout of the design (shown in Figure 3) consists of 36 placements of mrDANNA cores on the right side of the design with the left side containing a digital implementation of the architecture. The advantage of a mixed-signal design is that the connections with the outside signal

are fully digital whereas the integration within the core itself is analog. Hence, the mixed-signal memristive neuromorphic system discussed here is digital between cores and analog within the core. Moreover, the mixed-signal approach is also more energy efficient relative to other digital implementations. Since mixed-signal models provide the opportunity to implement synapse and neuron models with better area and power efficiency, we are inclined towards improving the design of our neuromorphic cores for use in multiple different applications including classification, control and anomaly detection.

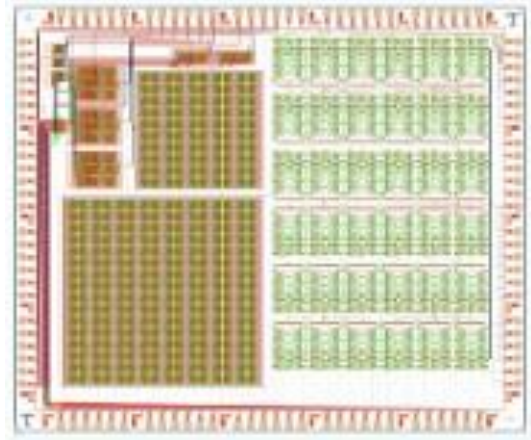


Figure 3: Final layout of first generation mrDANNA test chip submitted for fabrication [4].

3 FUTURE WORK AND CONCLUSIONS

The era of IoT devices has compelled us to consider such technologies with opportunities that introduce resource constrained devices having area and power efficiency. Since we are looking at neuromorphic computing with emergent devices, our primary goal is to ensure energy and area efficiency with proper architecture.

In this work, we have shown that a network for a neuromorphic architecture using emerging devices (mrDANNA) can be generated using evolutionary optimization to perform an autonomous robot navigation task. The resulting network is relatively small and sparse when compared with most deep learning networks, resulting in area efficiency, while also maintaining power efficiency (142.7 μ W).

There is much future work to be done with respect to neuromorphic computing and IoT devices. One potential future direction is the aggregation of data communication among devices connected to each other. Because of the potential power of spiky neuromorphic systems in analyzing streaming data, we also anticipate that neuromorphic systems will play a large role in data analysis at

the “edge.” Our utilization of EO for training has tended to produce smaller, sparser networks than what is typically seen in deep learning networks, making them well-suited for deployment onto physical, resource-constrained devices. Moreover, we also intend to explore utilizing on-chip plasticity mechanisms to continue learning or training on the device itself. These types of mechanisms will potentially allow for adapting and self-healing systems in the future, which will be especially important for IoT devices that are in remote areas and not easily accessible. We envision to continue our research in the area of big data analysis while ensuring low energy and area consumption for largely connected IoT devices.

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